QIE10-11 Readout Chip Development

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FEE 2014 Argonne National Laboratory May 20, 2014

Overview of multi-decade QIE development

- The QIE [Charge (<u>Q</u>) <u>Integrator and Encoder</u>] is a custom ASIC designed to digitize wide dynamic range charge signals from photo-detectors (PMTs, SiPMs), with approximately constant resolution and no deadtime
- A short history:
 - 1989: Originally conceived by Bill Foster for SDC @ SSC
 - 1995: 1st fully-functional chip designed by Tom Zimmerman for the KTeV experiment @ FNAL (QIE5)
 - 2 µm Orbit "Bi-CMOS", 3000 ch.
 - 1996: Front-end for calorimeters of CDF @ FNAL (QIE6)
 - 2 μm Orbit "Bi-CMOS", 10,000 ch.
 - 2002: Front-end for MINOS Near Detector @ FNAL (QIE7)
 - 2 µm Orbit "Bi-CMOS", 10,000 ch.
 - 2003: Front-end for CMS HCAL @ CERN (QIE8)
 - 0.8 μm AMS BiCMOS, 10,000 ch. .
 - 2004: Front-end for BTEV @ FNAL (cancelled) (QIE9)
 - 0.8 µm AMS BiCMOS
 - 2013-14: Front-end for CMS forward calorimeter (QIE10) Barrel and endcap calorimeters (QIE11)
 - 0.35 µm AMS SiGe BiCMOS













All QIE chips are based on the NPN bipolar current splitter concept:

To multi-range integrator inputs



The current split ratios are determined by NPN emitter area ratios (using multiples of a unit transistor). Split ratios remain <u>constant</u> over a big dynamic range, even in the presence of mismatch (<u>not</u> true for MOS)!

Therefore, all QIE chips are realized using a BiCMOS process.

Overview of QIE10

- The newest design (**QIE10**) features:
 - Dead-timeless operation @ 40 MHz, using 4-phase operation (same as all previous QIEs)
 - High dynamic range: 3 fC − 330 pC (~17 bits). 6-bit mantissa, 4 Ranges → 256 codes (10X the range of QIE8)
 - Logarithmic response ~1% measurement across dynamic range
 - Controlled impedance input over full dynamic range (5 meter input cable from PMT)
 - 6 bit TDC (0.5 ns) with programmable threshold (first QIE with a TDC)
 - Serial download of programmable parameters (new feature)
 - True LVDS outputs
 - On-chip test charge injection
 - Low power: 320 mW
 - +5V @ 40 mA analog
 - +3.3V @ 35 mA digital
 - 350 nm AMS SiGe process
 (first QIE to use this process)



Non-inverting amp/splitter (negative input current)

Overview of QIE11

- Similar to QIE10 with the following differences:
 - Intended for SiPM readout
 - Programmable input current shunt to achieve scaling factors of:

x1, x1.5, x2, x3, x4, x6, x8, x12 (in order to accommodate higher than anticipated SiPM gain)

 Lowest possible input impedance (not constant, impedance naturally goes down as signal magnitude goes up)

- How the QIE10 works:
 - * Receives charge (current) from PMT Anode
 - ***** "Splits" current into four weighted *Ranges*
 - * Gates and integrates current fractions onto separate capacitors
 - * Based on the signal magnitude, 1 of the 4 Ranges is selected to be digitized
 - Ranges are logarithmically weighted (X8)
 - ★ Digitizes the analog voltage from the selected Range
 - 6-bit FADC with *logarithmic* response (bin width 1, 2, 4, 8) \rightarrow "Mantissa"
 - ***** Outputs 2-bit code for the Range digitized (0 3) \rightarrow "Exponent"

⇒ Produces floating-point output codes

⇒ Response is approximately logarithmic...



In reality, 4 sets of integrators (4 phases A-D) are used to achieve dead-timeless operation:

- Operations are pipelined at 40 MHz using 4-phase circuits ⇒ Produces a code
- Data includes 2-bit CapID to indicate phase

representing the current integrated in each and every 25 ns period <u>and never stops</u>



- Splitter/integrator implementation:
 - 24 identical NPN transistors, arranged in groups: x16, x4, x2, x1, x1
 - Integrator capacitor ratios: 1, 2, 8, 32
 - Results in 4 integration ranges, each scaled by X8
 - Selected integrator feeds a 4-section ADC with binary weighted bin widths
 - Results in effectively 16 ranges, scaled by x2



phases shown

Shown as single-ended implementation, actually done in pseudo-differential form (shown later)



Controlled impedance input amplifier/splitter design challenges

- Constant split ratio over wide dynamic range: NPN splitter required (not NMOS)
- Small DC input bias current (< 20 uA)

g_{m1} goes up with I_{SIG}, so open-loop

gain and R_{IN} changes with I_{SIG}!

• Constant impedance input for 0 – 60 mA input current: requires novel feedback amp approach



For the <u>biggest</u> signals (>> 1mA), M₂ is debiased, and Q₁ functions as an open-loop common base amp, with input resistance set by R_{EXTERNAL}.

Tune V_{DC} and $R_{EXTERNAL}$ for $R_{IN} = 20$ ohms. 10

<u>A crucial QIE strategy:</u> Implement all analog circuits in pseudo-differential form: 2 "identical" inputs -- signal source connects to the *SIG* input, and the *REF* input floats

RESULT: excellent stability and common-mode rejection

(relatively immune to shifts in bias levels, supply voltage, clock frequency, temperature, etc.)



Pseudo-differential TDC implementation



Pseudo-differential Flash ADC implementation



Another crucial QIE strategy: Create isolated substrate areas on the same chip. Reference them all to the die pad ("system ground"). This greatly reduces digital-to-analog coupling!



Put it all together: QIE10 full chip block diagram



QIE10 Test Results

- LSB = 3 fC (as expected)
- Input impedance stable over complete dynamic range
- Noise with 5 meter RG58 input cables: 1.8 fC (input referred)
- Noise with short (0.2 meter) RC58 input cables: 0.6 fC
- No change in pedestals or noise after 50 KRad TID (Cs-137 source)
- No SEUs in shadow register holding programmed values after 6E12 p/cm2 (230 MeV proton beam)



Measured QIE10 input resistance over full dynamic range



(DAC provided for tweaking of input resistance at low end)

Range 1 Mantissa Versus Input Charge



Response as expected
 Note: Uses capID pedestal adjust feature to make pedestals uniform

Study of bin widths in the 4-section ADC:



- ⇒ See nice uniform bin widths
- ⇒ Bin width variation minimized in bottom 2 sections by design (small bin size requires less variation than large bin to achieve the same DNL)

- Timing Studies TDC Response
 - Apply external input pulse (well above TDC threshold).
 - Step pulse delay by 50 ps, average 100 data points per setting



TDC Code Versus Pulse Delay For Chip X

Data from Fermilab

⇒ See nice linear response

⇒ Bin width uniformity is good: average width = 0.50 ns, DNL < 0.1 ns

QIE11 (SiPM readout chip)

- Non-inverting input (same as QIE10)
- Current shunt provides programmable gain to accommodate big SiPM signals
- Low input impedance for big signals (remove constant impedance circuit)
- Full-chip prototype works well (x5 shunt) with only a couple of small bugs



Input resistance ~15 ohms for small signal, no shunt

Input resistance ~1 ohm for largest signal, big shunt

QIE: a success story over 25 years!

Future QIE work this year:

- Modification of QIE11 for ATLAS: add another bit of resolution (7-bit mantissa)
- Quad QIE (4 per package)??